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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

E·XFI

Product Status	Obsolete
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I ² C, IrDA, LINbus, MMC/SD/SDIO, QSPI, SmartCard, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, DMA, LCD, POR, PWM, WDT
Number of I/O	50
Program Memory Size	2MB (2M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	512K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 16x12b SAR; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-VFQFN Exposed Pad
Supplier Device Package	64-QFN (9x9)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32gg11b820f2048gm64-ar

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

4.1.1 Absolute Maximum Ratings

Stresses above those listed below may cause permanent damage to the device. This is a stress rating only and functional operation of the devices at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability. For more information on the available quality and reliability data, see the Quality and Reliability Monitor Report at http://www.silabs.com/support/quality/pages/default.aspx.

Table 4.1. Absolute Maximum Ratings

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Storage temperature range	T _{STG}		-50	—	150	°C
Voltage on supply pins other than VREGI and VBUS	V _{DDMAX}		-0.3	_	3.8	V
Voltage ramp rate on any supply pin	V _{DDRAMPMAX}		_	_	1	V / µs
DC voltage on any GPIO pin	V _{DIGPIN}	5V tolerant GPIO pins ^{1 2 3}	-0.3	—	Min of 5.25 and IOVDD +2	V
		LCD pins ³	-0.3	_	Min of 3.8 and IOVDD +2	V
		Standard GPIO pins	-0.3	_	IOVDD+0.3	V
Total current into VDD power lines	I _{VDDMAX}	Source	_	_	200	mA
Total current into VSS ground lines	I _{VSSMAX}	Sink	_	_	200	mA
Current per I/O pin	I _{IOMAX}	Sink	_	_	50	mA
		Source	_	_	50	mA
Current for all I/O pins	IIOALLMAX	Sink	_	_	200	mA
		Source	_	_	200	mA
Junction temperature	TJ	-G grade devices	-40	_	105	°C
		-I grade devices	-40	—	125	°C
Voltage on regulator supply pins VREGI and VBUS	V _{VREGI}		-0.3	_	5.5	V

Note:

1. When a GPIO pin is routed to the analog module through the APORT, the maximum voltage = IOVDD.

 Valid for IOVDD in valid operating range or when IOVDD is undriven (high-Z). If IOVDD is connected to a low-impedance source below the valid operating range (e.g. IOVDD shorted to VSS), the pin voltage maximum is IOVDD + 0.3 V, to avoid exceeding the maximum IO current specifications.

3. To operate above the IOVDD supply rail, over-voltage tolerance must be enabled according to the GPIO_Px_OVTDIS register. Pins with over-voltage tolerance disabled have the same limits as Standard GPIO.

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Current consumption in EM0 mode with all peripherals dis-	IACTIVE_LPM	32 MHz HFRCO, CPU running while loop from flash	_	82	_	µA/MHz
abled, DCDC in LP mode ³		26 MHz HFRCO, CPU running while loop from flash	—	83	_	µA/MHz
		16 MHz HFRCO, CPU running while loop from flash	_	88	_	µA/MHz
		1 MHz HFRCO, CPU running while loop from flash	—	257	_	µA/MHz
Current consumption in EM0 mode with all peripherals dis-	IACTIVE_CCM_VS	19 MHz HFRCO, CPU running while loop from flash	_	117	_	µA/MHz
abled and voltage scaling enabled, DCDC in Low Noise CCM mode ¹		1 MHz HFRCO, CPU running while loop from flash	_	1231	_	µA/MHz
Current consumption in EM0 mode with all peripherals dis-	IACTIVE_LPM_VS	19 MHz HFRCO, CPU running while loop from flash	—	72		µA/MHz
abled and voltage scaling enabled, DCDC in LP mode ³		1 MHz HFRCO, CPU running while loop from flash	—	219		µA/MHz
Current consumption in EM1	I _{EM1_DCM}	72 MHz HFRCO	—	42	_	µA/MHz
mode with all peripherals dis- abled, DCDC in Low Noise		50 MHz crystal	—	46	_	µA/MHz
DCM mode ²		48 MHz HFRCO	—	46	_	µA/MHz
		32 MHz HFRCO	—	53	_	µA/MHz
		26 MHz HFRCO	—	57	_	µA/MHz
		16 MHz HFRCO	—	72	_	µA/MHz
		1 MHz HFRCO	—	663	_	µA/MHz
Current consumption in EM1	I _{EM1_LPM}	32 MHz HFRCO	—	42	—	µA/MHz
mode with all peripherals dis- abled, DCDC in Low Power		26 MHz HFRCO	—	43	—	µA/MHz
mode ³		16 MHz HFRCO	—	48	_	µA/MHz
		1 MHz HFRCO	_	219	_	µA/MHz
Current consumption in EM1	I _{EM1_DCM_VS}	19 MHz HFRCO	—	60	—	µA/MHz
mode with all peripherals dis- abled and voltage scaling enabled, DCDC in Low Noise DCM mode ²		1 MHz HFRCO	_	637	_	µA/MHz
Current consumption in EM1	I _{EM1_LPM_VS}	19 MHz HFRCO	_	39	_	µA/MHz
mode with all peripherals dis- abled and voltage scaling enabled. DCDC in LP mode ³		1 MHz HFRCO	—	190	_	µA/MHz
Current consumption in EM2 mode, with voltage scaling	I _{EM2_VS}	Full 512 kB RAM retention and RTCC running from LFXO	_	2.8	_	μΑ
enabled, DCDC in LP mode ³		Full 512 kB RAM retention and RTCC running from LFRCO	—	3.1	_	μΑ
		16 kB (1 bank) RAM retention and RTCC running from LFRCO ⁵	—	2.1	_	μΑ
Current consumption in EM3 mode, with voltage scaling enabled	I _{EM3_VS}	Full 512 kB RAM retention and CRYOTIMER running from ULFR- CO	_	2.4	_	μA

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
Output fall time, From 70%	t _{IOOF}	C _L = 50 pF,	—	1.8	_	ns
to 30% of V _{IO}		DRIVESTRENGTH ¹ = STRONG,				
		SLEWRATE ¹ = 0x6				
		C _L = 50 pF,		4.5	_	ns
		DRIVESTRENGTH ¹ = WEAK,				
		SLEWRATE ¹ = 0x6				
Output rise time, From 30%	t _{IOOR}	C _L = 50 pF,		2.2	_	ns
to 70% of V _{IO}		DRIVESTRENGTH ¹ = STRONG,				
		SLEWRATE = 0x6 ¹				
		C _L = 50 pF,		7.4	_	ns
		DRIVESTRENGTH ¹ = WEAK,				
		SLEWRATE ¹ = 0x6				
Note:						

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Supply current, continuous conversions, WARMUP- MODE=KEEPCSENWARM	ICSEN_ACTIVE	SAR or Delta Modulation conver- sions of 33 pF capacitor, CS0CG=0 (Gain = 10x), always on	_	90.5	_	μA
HFPERCLK supply current	ICSEN_HFPERCLK	Current contribution from HFPERCLK when clock to CSEN block is enabled.		2.25	_	µA/MHz

Note:

 Current is specified with a total external capacitance of 33 pF per channel. Average current is dependent on how long the module is actively sampling channels within the scan period, and scales with the number of samples acquired. Supply current for a specific application can be estimated by multiplying the current per sample by the total number of samples per period (total_current = single_sample_current * (number_of_channels * accumulation)).

EBI Read Enable Output Timing

Timing applies to both EBI_REn and EBI_NANDREn for all addressing modes and both polarities. Output timing for EBI_AD applies only to multiplexed addressing modes D8A24ALE and D16A16ALE. All numbers are based on route locations 0,1,2 only (with all EBI alternate functions using the same location at the same time). Timing is specified at 10% and 90% of IOVDD, 25 pF external loading, and slew rate for all GPIO set to 6.

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Output hold time, from trail- ing EBI_REn / EBI_NAN- DREn edge to EBI_AD, EBI_A, EBI_CSn, EBI_BLn invalid	t _{OH_REn}	IOVDD ≥ 1.62 V	-23 + (RDHOLD * ^t HFCOR- ECLK)	_	_	ns
		IOVDD ≥ 3.0 V	-13 + (RDHOLD * ^t HFCOR- ECLK)	_	_	ns
Output setup time, from EBI_AD, EBI_A, EBI_CSn, EBI_BLn valid to leading EBI_REn / EBI_NANDREn edge ¹	t _{OSU_REn}	IOVDD ≥ 1.62 V	-12 + (RDSETUP * t _{HFCOR-} ECLK)	_	_	ns
euge ·		IOVDD ≥ 3.0 V	-11 + (RDSETUP ^{* t} HFCOR- ECLK)	_	_	ns
EBI_REn pulse width ^{1 2}	twiDTH_REn	IOVDD ≥ 1.62 V	-6 + (MAX(1, RDSTRB) * t _{HFCOR-} ECLK)	_	_	ns
		IOVDD ≥ 3.0 V	-4 + (MAX(1, RDSTRB) * t _{HFCOR-} ECLK)	—	_	ns

Table 4.38. EBI Read Enable Output Timing

Note:

1. The figure shows the timing for the case that the half strobe length functionality is not used, i.e. HALFRE=0. The leading edge of EBI_REn can be moved to the right by setting HALFRE=1. This decreases the length of t_{WIDTH_REn} and increases the length of t_{OSU_REn} by 1/2 * t_{HFCLKNODIV}.

2. When page mode is used, RDSTRB is replaced by RDPA for page hits.

4.1.27 Serial Data I/O Host Controller (SDIO)

SDIO DS Mode Timing

Timing is specified for route location 0 at 3.0 V IOVDD with voltage scaling disabled. Slew rate for SD_CLK set to 6, all other GPIO set to 6, DRIVESTRENGTH = STRONG for all pins. SDIO_CTRL_TXDLYMUXSEL = 1. Loading between 5 and 10 pF on all pins or between 10 and 40 pF on all pins.

Table 4.46. SDIO DS Mode Timing (Location 0)

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
Clock frequency during data transfer	F _{SD_CLK}	Using HFRCO, AUXHFRCO, or USHFRCO	-		23	MHz
		Using HFXO	_	_	TBD	MHz
Clock low time	t _{WL}	Using HFRCO, AUXHFRCO, or USHFRCO	19.7		_	ns
		Using HFXO	TBD	_	_	ns
Clock high time	t _{WH}	Using HFRCO, AUXHFRCO, or USHFRCO	19.7	_	_	ns
		Using HFXO	TBD	_	_	ns
Clock rise time	t _R		1.69	3.23	_	ns
Clock fall time	t _F		1.42	2.79	_	ns
Input setup time, CMD, DAT[0:3] valid to SD_CLK	t _{ISU}		6	_	_	ns
Input hold time, SD_CLK to CMD, DAT[0:3] change	t _{IH}		0	_	_	ns
Output delay time, SD_CLK to CMD, DAT[0:3] valid	t _{ODLY}		0		14	ns
Output hold time, SD_CLK to CMD, DAT[0:3] change	t _{OH}		5	_	_	ns

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
IOVDD1	F7 G7	Digital IO power supply 1.	VSS	F8 G8 G9 H6 H7 H8 H9 H10 H11 J6 J7 J8 J9 J10 J11 K8 K9 L8 L9	Ground
NC	F9	No Connect.	IOVDD0	F10 F11 G10 G11 K6 K7 K10 K11 L6 L7 L10 L11	Digital IO power supply 0.
PI5	F14	GPIO (5V)	Pl4	F15	GPIO (5V)
PI3	F16	GPIO (5V)	PA5	G1	GPIO
PG6	G2	GPIO (5V)	PG5	G3	GPIO (5V)
PI2	G14	GPIO (5V)	PI1	G15	GPIO (5V)
PI0	G16	GPIO (5V)	PA6	H1	GPIO
PG8	H2	GPIO (5V)	PG7	H3	GPIO (5V)
PE5	H14	GPIO	PE6	H15	GPIO
PE7	H16	GPIO	PG11	J1	GPIO (5V)
PG10	J2	GPIO (5V)	PG9	J3	GPIO (5V)
PE3	J14	GPIO	PE4	J15	GPIO
DECOUPLE	J16	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.	PG14	K1	GPIO
PG13	K2	GPIO	PG12	K3	GPIO
PE1	K14	GPIO (5V)	PE2	K15	GPIO
DVDD	K16	Digital power supply.	PG15	L1	GPIO (5V)
PB15	L2	GPIO (5V)	PB0	L3	GPIO
PE0	L14	GPIO (5V)	PC7	L15	GPIO
VREGVDD	L16	Voltage regulator VDD input	PB1	M1	GPIO

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PG6	H1	GPIO (5V)	PG7	H2	GPIO (5V)
PG5	H3	GPIO (5V)	PE6	H12	GPIO
PE5	H13	GPIO	DVDD	H14	Digital power supply.
PG9	J1	GPIO (5V)	PG10	J2	GPIO (5V)
PG8	J3	GPIO (5V)	PE3	J12	GPIO
PE4	J13	GPIO	VREGVDD	J14	Voltage regulator VDD input
PG12	K1	GPIO	PG13	K2	GPIO
PG11	K3	GPIO (5V)	PE2	K12	GPIO
PE1	K13	GPIO (5V)	VREGSW	K14	DCDC regulator switching node
PG15	L1	GPIO (5V)	PB15	L2	GPIO (5V)
PG14	L3	GPIO	PC7	L12	GPIO
PE0	L13	GPIO (5V)	VREGVSS	L14	Voltage regulator VSS
PB0	M1	GPIO	PB1	M2	GPIO
PB4	M3	GPIO	PC0	M4	GPIO (5V)
PC3	M5	GPIO (5V)	PA9	M6	GPIO
BODEN	M7	Brown-Out Detector Enable. This pin may be left disconnected or tied to AVDD.	PA12	M8	GPIO (5V)
RESETn	M9	Reset input, active low. To apply an ex- ternal reset source to this pin, it is re- quired to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.	PB10	M10	GPIO (5V)
PD1	M11	GPIO	PC6	M12	GPIO
PD5	M13	GPIO	PD8	M14	GPIO
PB7	N1	GPIO	PB2	N2	GPIO
PB5	N3	GPIO	PC2	N4	GPIO (5V)
PC5	N5	GPIO	PA8	N6	GPIO
PA11	N7	GPIO	PA14	N8	GPIO
PB11	N9	GPIO	PB12	N10	GPIO
PD0	N11	GPIO (5V)	PD2	N12	GPIO (5V)
PD4	N13	GPIO	PD7	N14	GPIO
PB8	P1	GPIO	PB3	P2	GPIO
PB6	P3	GPIO	PC1	P4	GPIO (5V)
PC4	P5	GPIO	PA7	P6	GPIO
PA10	P7	GPIO	PA13	P8	GPIO (5V)
PB9	P9	GPIO (5V)	PB13	P10	GPIO
PB14	P11	GPIO	AVDD	P12	Analog power supply.
PD3	P13	GPIO	PD6	P14	GPIO

5.7 EFM32GG11B3xx in BGA112 Device Pinout

Pin A1 index	1	2	3	4	5	6	7	8	9	10	11
А	The second secon	PELA	PE12	PE9	6010	(PFT)	(PF5)	(PFA)	PEA	PC14	6C15
B C	ertag (Lag	PE13 PAO	PE11 PE10	PE8 PD13	6013 6013	PF8 PF9	pr6	PF3 PF2	PES PEO	6C13	6C13
D	(PA3)	(PA2)	PB1 ⁵	155	LOVODI	<i>60d</i>	101000	PFI	PET	(⁸)9	(P29)
E	PAG	PAS	PAA	<i>PB0</i>				PFO	PEO	PEL	PE3
F	PBI	P82	PB3	PB ⁴				pupp	(15 ⁵)	PE2	DECOUPLE
G	PB5	(PB6)	N55	100002				101000	(15 ⁵)	<i>6</i> 09	(PC1)
Н	(PC)	PC2	6014	(TA9)	849	155	TONDO	(PD8)	P05	609	(Tag
J	PCJ	(PC3)	013	PAIZ	(PA9)	PALO	68 ∂	PB10	605	(PD3)	(ADG)
К	PBT	PCA	PA13	155	PA14	RESET	N 55	ANDO	AVDO	155	10g
L	688	P ⁽⁵⁾	PALA	10000	PBLI	6812	(155)	6813	PB14	AVOD	600

Figure 5.7. EFM32GG11B3xx in BGA112 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see 5.20 GPIO Functionality Table or 5.21 Alternate Functionality Overview.

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PE15	A1	GPIO	PE14	A2	GPIO
PE12	A3	GPIO	PE9	A4	GPIO
PD10	A5	GPIO	PF7	A6	GPIO
PF5	A7	GPIO	PF4	A8	GPIO
PE4	A9	GPIO	PC14	A10	GPIO (5V)
PC15	A11	GPIO (5V)	PA15	B1	GPIO
PE13	B2	GPIO	PE11	В3	GPIO

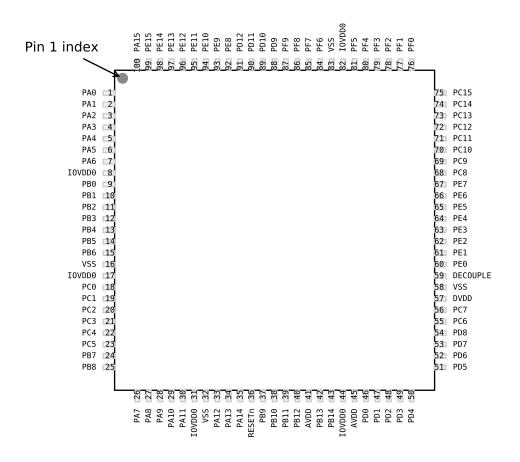


Figure 5.11. EFM32GG11B3xx in QFP100 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see 5.20 GPIO Functionality Table or 5.21 Alternate Functionality Overview.

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	PA3	4	GPIO
PA4	5	GPIO	PA5	6	GPIO
PA6	7	GPIO	IOVDD0	8 17 31 44 82	Digital IO power supply 0.
PB0	9	GPIO	PB1	10	GPIO

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PB2	11	GPIO	PB3	12	GPIO
PB4	13	GPIO	PB5	14	GPIO
PB6	15	GPIO	VSS	16 32 58 83	Ground
PC0	18	GPIO (5V)	PC1	19	GPIO (5V)
PC2	20	GPIO (5V)	PC3	21	GPIO (5V)
PC4	22	GPIO	PC5	23	GPIO
PB7	24	GPIO	PB8	25	GPIO
PA7	26	GPIO	PA8	27	GPIO
PA9	28	GPIO	PA10	29	GPIO
PA11	30	GPIO	PA12	33	GPIO (5V)
PA13	34	GPIO (5V)	PA14	35	GPIO
RESETn	36	Reset input, active low. To apply an ex- ternal reset source to this pin, it is re- quired to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.	PB9	37	GPIO (5V)
PB10	38	GPIO (5V)	PB11	39	GPIO
PB12	40	GPIO	AVDD	41 45	Analog power supply.
PB13	42	GPIO	PB14	43	GPIO
PD0	46	GPIO (5V)	PD1	47	GPIO
PD2	48	GPIO (5V)	PD3	49	GPIO
PD4	50	GPIO	PD5	51	GPIO
PD6	52	GPIO	PD7	53	GPIO
PD8	54	GPIO	PC6	55	GPIO
PC7	56	GPIO	DVDD	57	Digital power supply.
DECOUPLE	59	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.	PE0	60	GPIO (5V)
PE1	61	GPIO (5V)	PE2	62	GPIO
PE3	63	GPIO	PE4	64	GPIO
PE5	65	GPIO	PE6	66	GPIO
PE7	67	GPIO	PC8	68	GPIO (5V)
PC9	69	GPIO (5V)	PC10	70	GPIO (5V)
PC11	71	GPIO (5V)	PC12	72	GPIO (5V)
PC13	73	GPIO (5V)	PC14	74	GPIO (5V)
PC15	75	GPIO (5V)	PF0	76	GPIO (5V)
PF1	77	GPIO (5V)	PF2	78	GPIO

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PB6	12	GPIO	PC4	13	GPIO
PC5	14	GPIO	PB7	15	GPIO
PB8	16	GPIO	PA8	17	GPIO
PA12	18	GPIO (5V)	PA13	19	GPIO (5V)
PA14	20	GPIO	RESETn	21	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensur that reset is released.
PB11	22	GPIO	PB12	23	GPIO
AVDD	24	Analog power supply.	PB13	25	GPIO
PB14	26	GPIO	PD0	28	GPIO (5V)
PD1	29	GPIO	PD2	30	GPIO (5V)
PD3	31	GPIO	PD4	32	GPIO
PD5	33	GPIO	PD6	34	GPIO
PD7	35	GPIO	PD8	36	GPIO
PC7	37	GPIO	VREGVSS	38	Voltage regulator VSS
VREGSW	39	DCDC regulator switching node	VREGVDD	40	Voltage regulator VDD input
DVDD	41	Digital power supply.	DECOUPLE	42	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.
PE4	43	GPIO	PE5	44	GPIO
PE6	45	GPIO	PE7	46	GPIO
PC12	47	GPIO (5V)	PC13	48	GPIO (5V)
PF0	49	GPIO (5V)	PF1	50	GPIO (5V)
PF2	51	GPIO	PF3	52	GPIO
PF4	53	GPIO	PF5	54	GPIO
PE8	56	GPIO	PE9	57	GPIO
PE10	58	GPIO	PE11	59	GPIO
PE12	60	GPIO	PE13	61	GPIO
PE14	62	GPIO	PE15	63	GPIO
PA15	64	GPIO	1		

1. GPIO with 5V tolerance are indicated by (5V).

5.20 GPIO Functionality Table

A wide selection of alternate functionality is available for multiplexing to various pins. The following table shows the name of each GPIO pin, followed by the functionality available on that pin. Refer to 5.21 Alternate Functionality Overview for a list of GPIO locations available for each function.

GPIO Name	Pin Alternate Functionality / Description						
	Analog	EBI	Timers	Communication	Other		
PA15	BUSAY BUSBX LCD_SEG12	EBI_AD08 #0	TIM3_CC2 #0	ETH_MIIRXCLK #0 ETH_MDIO #3 US2_CLK #3	PRS_CH15 #0		
PE15	BUSCY BUSDX LCD_SEG11	EBI_AD07 #0	TIM2_CDTI2 #2 TIM3_CC1 #0	ETH_RMIITXD0 #0 ETH_MIIRXD3 #0 SDIO_CMD #1 US0_RTS #0 QSPI0_DQS #1 LEU0_RX #2	PRS_CH14 #2 ETM_TD3 #4		
PE14	BUSDY BUSCX LCD_SEG10	EBI_AD06 #0	TIM2_CDTI1 #2 TIM3_CC0 #0	ETH_RMIITXD1 #0 ETH_MIIRXD2 #0 SDIO_CLK #1 US0_CTS #0 QSPI0_SCLK #1 LEU0_TX #2	PRS_CH13 #2 ETM_TD2 #4		
PE13	BUSCY BUSDX LCD_SEG9	EBI_AD05 #0	TIM1_CC3 #1 TIM2_CC2 #3 LE- TIM0_OUT1 #4	SDIO_CLK #0 ETH_MIIRXD1 #0 US0_TX #3 US0_CS #0 U1_RX #4 I2C0_SCL #6	LES_ALTEX7 PRS_CH2 #3 ACMP0_O #0 ETM_TD1 #4 GPIO_EM4WU5		
PE12	BUSDY BUSCX LCD_SEG8	EBI_AD04 #0	TIM1_CC2 #1 TIM2_CC1 #3 WTIM0_CDTI2 #0 LETIM0_OUT0 #4	SDIO_CMD #0 ETH_MIIRXD0 #0 US0_RX #3 US0_CLK #0 U1_TX #4 I2C0_SDA #6	CMU_CLK1 #2 CMU_CLKI0 #6 LES_ALTEX6 PRS_CH1 #3 ETM_TD0 #4		
PE11	BUSCY BUSDX LCD_SEG7	EBI_AD03 #0 EBI_CS3 #4	TIM1_CC1 #1 TIM4_CC2 #7 WTIM0_CDTI1 #0	SDIO_DAT0 #0 QSPI0_DQ7 #0 ETH_MIIRXDV #0 US0_RX #0	LES_ALTEX5 PRS_CH3 #2 ETM_TCLK #4		
PE10	BUSDY BUSCX LCD_SEG6	EBI_AD02 #0 EBI_CS2 #4	TIM1_CC0 #1 TIM4_CC1 #7 WTIM0_CDTI0 #0	SDIO_DAT1 #0 QSPI0_DQ6 #0 ETH_MIIRXER #0 US0_TX #0	PRS_CH2 #2 GPIO_EM4WU9		
PE9	BUSCY BUSDX LCD_SEG5	EBI_AD01 #0 EBI_CS1 #4	TIM4_CC0 #7 PCNT2_S1IN #1	SDIO_DAT2 #0 QSPI0_DQ5 #0 US5_RX #0	PRS_CH8 #2		
PE8	BUSDY BUSCX LCD_SEG4	EBI_AD00 #0 EBI_CS0 #4	TIM2_CDTI0 #2 TIM4_CC2 #6 PCNT2_S0IN #1	SDIO_DAT3 #0 QSPI0_DQ4 #0 US5_TX #0 I2C2_SDA #0	PRS_CH3 #1		
PI9		EBI_A14 #2	TIM1_CC3 #7 TIM4_CC1 #3	US4_CS #3			
PI6		EBI_A11 #2	TIM1_CC0 #7 TIM4_CC1 #2 WTIM3_CC0 #5	US4_TX #3			

Table 5.20. GPIO Functionality Table

5.21 Alternate Functionality Overview

A wide selection of alternate functionality is available for multiplexing to various pins. The following table shows the name of the alternate functionality in the first column, followed by columns showing the possible LOCATION bitfield settings and the associated GPIO pin. Refer to 5.20 GPIO Functionality Table for a list of functions available on each GPIO pin.

Note: Some functionality, such as analog interfaces, do not have alternate settings or a LOCATION bitfield. In these cases, the pinout is shown in the column corresponding to LOCATION 0.

Alternate LOCATION		ATION	
Functionality	0 - 3	4 - 7	Description
ACMP0_O	0: PE13 1: PE2 2: PD6 3: PB11	4: PA6 5: PB0 6: PB2 7: PB3	Analog comparator ACMP0, digital output.
ACMP1_O	0: PF2 1: PE3 2: PD7 3: PA12	4: PA14 5: PB9 6: PB10 7: PA5	Analog comparator ACMP1, digital output.
ACMP2_O	0: PD8 1: PE0 2: PE1 3: PI0	4: PI1 5: PI2	Analog comparator ACMP2, digital output.
ACMP3_O	0: PF0 1: PC15 2: PC14 3: PC13	4: PI4 5: PI5	Analog comparator ACMP3, digital output.
ADC0_EXTN	0: PD7		Analog to digital converter ADC0 external reference input negative pin.
ADC0_EXTP	0: PD6		Analog to digital converter ADC0 external reference input positive pin.
ADC1_EXTN	0: PD7		Analog to digital converter ADC1 external reference input negative pin.
ADC1_EXTP	0: PD6		Analog to digital converter ADC1 external reference input positive pin.
BOOT_RX	0: PF1		Bootloader RX.
BOOT_TX	0: PF0		Bootloader TX.

Table 5.21. Alternate Functionality Overview

Alternate	LOCA	TION	
Functionality	0 - 3	4 - 7	Description
	0: PF2		Debug-interface Serial Wire viewer Output.
DBG_SWO	1: PC15 2: PD1 3: PD2		Note that this function is not enabled after reset, and must be enabled by software to be used.
	0: PF5		Debug-interface JTAG Test Data In.
DBG_TDI			Note that this function becomes available after the first valid JTAG command is received, and has a built-in pull up when JTAG is active.
	0: PF2		Debug-interface JTAG Test Data Out.
DBG_TDO			Note that this function becomes available after the first valid JTAG command is received.
EBI_A00	0: PA12 1: PB9 2: PE0 3: PC5		External Bus Interface (EBI) address output pin 00.
EBI_A01	0: PA13 1: PB10 2: PE1 3: PA7		External Bus Interface (EBI) address output pin 01.
EBI_A02	0: PA14 1: PB11 2: PI0 3: PA8		External Bus Interface (EBI) address output pin 02.
EBI_A03	0: PB9 1: PB12 2: PI1 3: PA9		External Bus Interface (EBI) address output pin 03.
EBI_A04	0: PB10 1: PD0 2: PI2 3: PA10		External Bus Interface (EBI) address output pin 04.
EBI_A05	0: PC6 1: PD1 2: PI3 3: PA11		External Bus Interface (EBI) address output pin 05.
EBI_A06	0: PC7 1: PD2 2: PI4 3: PA12		External Bus Interface (EBI) address output pin 06.
EBI_A07	0: PE0 1: PD3 2: PI5 3: PA13		External Bus Interface (EBI) address output pin 07.
EBI_A08	0: PE1 1: PD4 2: PC8 3: PA14		External Bus Interface (EBI) address output pin 08.
EBI_A09	0: PE2 1: PD5 2: PC9 3: PB9		External Bus Interface (EBI) address output pin 09.

Alternate	Alternate LOCATION		
Functionality	0 - 3	4 - 7	Description
LES_CH11	0: PC11		LESENSE channel 11.
LES_CH12	0: PC12		LESENSE channel 12.
LES_CH13	0: PC13		LESENSE channel 13.
LES_CH14	0: PC14		LESENSE channel 14.
LES_CH15	0: PC15		LESENSE channel 15.
LETIM0_OUT0	0: PD6 1: PB11 2: PF0 3: PC4	4: PE12 5: PC14 6: PA8 7: PB9	Low Energy Timer LETIM0, output channel 0.
LETIM0_OUT1	0: PD7 1: PB12 2: PF1 3: PC5	4: PE13 5: PC15 6: PA9 7: PB10	Low Energy Timer LETIM0, output channel 1.
LETIM1_OUT0	0: PA7 1: PA11 2: PA12 3: PC2	4: PB5 5: PB2 6: PG0 7: PG2	Low Energy Timer LETIM1, output channel 0.
LETIM1_OUT1	0: PA6 1: PA13 2: PA14 3: PC3	4: PB6 5: PB1 6: PG1 7: PG3	Low Energy Timer LETIM1, output channel 1.
LEU0_RX	0: PD5 1: PB14 2: PE15 3: PF1	4: PA0 5: PC15	LEUART0 Receive input.
LEU0_TX	0: PD4 1: PB13 2: PE14 3: PF0	4: PF2 5: PC14	LEUART0 Transmit output. Also used as receive input in half duplex communication.
LEU1_RX	0: PC7 1: PA6 2: PD3 3: PB1	4: PB5 5: PH1	LEUART1 Receive input.
LEU1_TX	0: PC6 1: PA5 2: PD2 3: PB0	4: PB4 5: PH0	LEUART1 Transmit output. Also used as receive input in half duplex communication.

Dimension	Min	Тур	Мах			
A	0.78	0.84	0.90			
A1	0.13	0.18	0.23			
A3	0.17	0.21	0.25			
A2		0.45 REF				
D		7.00 BSC				
е	0.50 BSC					
E	7.00 BSC					
D1	6.00 BSC					
E1	6.00 BSC					
b	0.20 0.25 0.30					
ааа	0.10					
bbb	0.10					
ddd	0.08					
еее	0.15					
fff	0.05					
Noto	1					

Table 8.1. BGA120 Package Dimensions

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

3. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

Table 8.2. BGA120 PCB Land Pattern Dimensions

Min	Nom	Мах	
	0.20		
6.00			
6.00			
	0.5		
	0.5		
	Min	0.20 6.00 6.00 0.5	

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.

3. This Land Pattern Design is based on the IPC-7351 guidelines.

4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 μm minimum, all the way around the pad.

5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.

6. The stencil thickness should be 0.125 mm (5 mils).

7. The ratio of stencil aperture to land pad size should be 1:1.

8. A No-Clean, Type-3 solder paste is recommended.

9. The recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

Table 9.2. BGA112 PCB Land Pattern Dimensions

Min	Nom	Мах
	0.45	
	8.00	
	8.00	
	0.8	
	0.8	
	Min	0.45 8.00 8.00 0.8

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.

3. This Land Pattern Design is based on the IPC-7351 guidelines.

4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 μm minimum, all the way around the pad.

5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.

6. The stencil thickness should be 0.125 mm (5 mils).

7. The ratio of stencil aperture to land pad size should be 1:1.

8. A No-Clean, Type-3 solder paste is recommended.

9. The recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.





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